

Supporting Information

Au-decorated Sb₂Se₃ photocathodes for solar-driven CO₂ reduction

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Figures



Figure S1. Photograph of the H-cell setup showing the cell holder made from PEEK. Exposed illuminated area is 0.28 cm^2 corresponding to a circular area with a diameter of 6 mm.

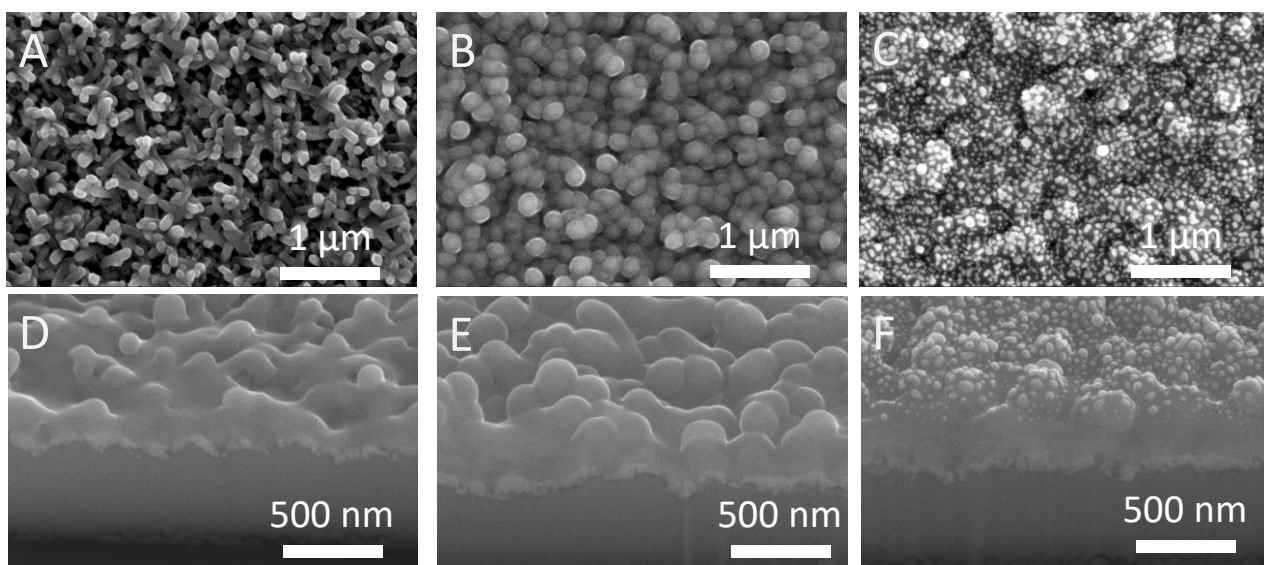


Figure S2. (A,B,C) Top-down and (D,E,F) Cross-section SEM images of (A,D) FTO/Au/Sb₂Se₃, (B,E) FTO/Au/Sb₂Se₃/TiO₂, and (C,F) FTO/Au/Sb₂Se₃/TiO₂/Au with 75 mC/cm^2 of charge passed for Au deposition at -0.25 V vs Ag/AgCl.

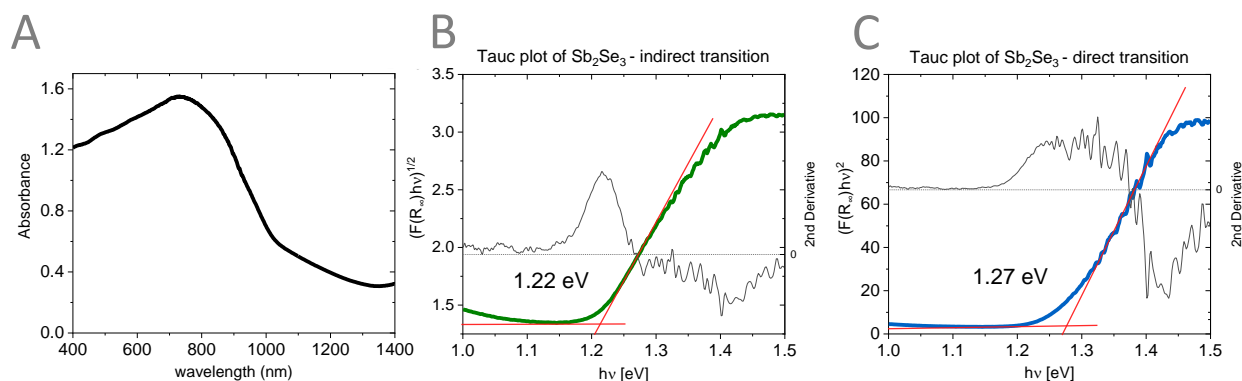


Figure S3. (A) UV Vis-NIR absorbance spectrum of the Sb₂Se₃ deposited on FTO with Tauc plots for band gap determination where (B) is for indirect transition analysis and (C) is for direct transition analysis. Sb₂Se₃ is reported to have very close indirect and direct transition.

Bandgap analysis: The bandgap analysis was done using the Tauc-plot method as seen in **Figure S3**. After measuring the diffused reflectance spectrum of Sb₂Se₃ deposited on FTO, the data was converted to the absorption spectrum using the Kubelka-Munk function.¹

To determine the bandgap, we plotted the corresponding $(F(R_{\infty})/hv)^{1/\gamma}$ vs hv for both indirect and direct transitions, where γ is 2 for indirect transitions and $\frac{1}{2}$ for direct transitions. The two types of transitions are known to exist for Sb₂Se₃.² These calculations led to the graphs in **Figure S3b** and **S3c**. On the resulting Tauc-plots, we determined the bandgap energy by linear fitting the steep region of the curves. To accurately determine the linear fit, the 2nd derivative method was used to find the inflection point on the curve. A tangent line on the inflection point of the curve was then drawn and extrapolated to the base to find the bandgap values.

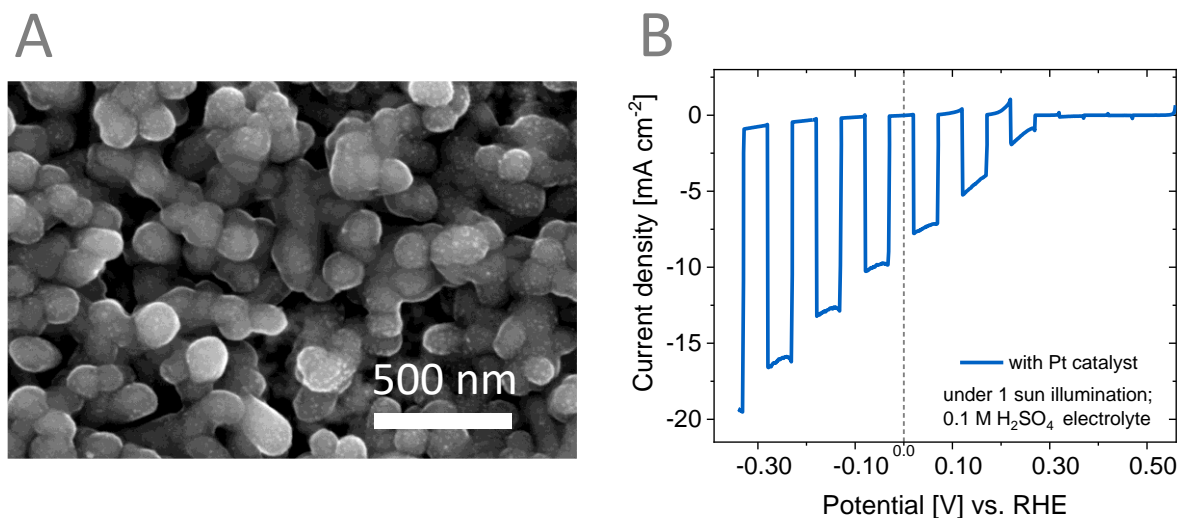


Figure S4. (A) SEM image of the photoelectrode with Pt cocatalyst. (B) Chopped light voltammogram of the photoelectrode with Pt catalyst for HER. Glassy carbon as counter electrode and Ag/AgCl as reference electrode.

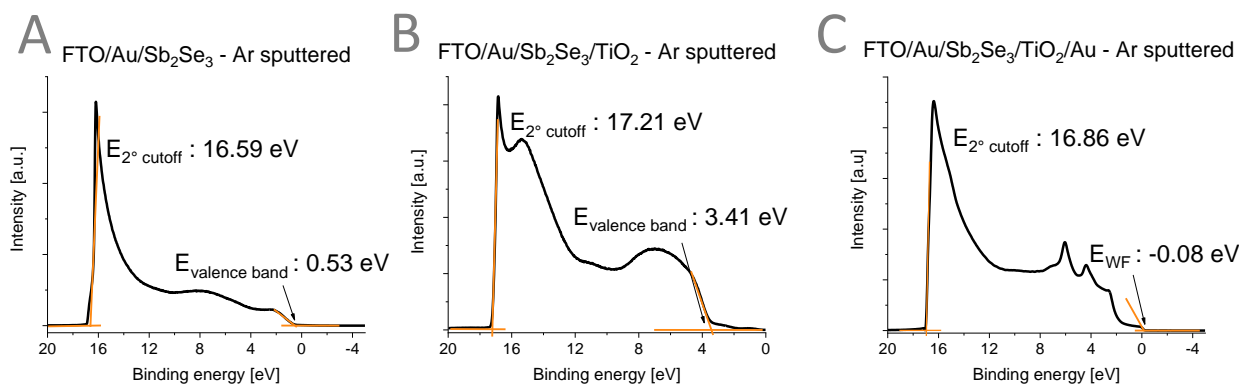


Figure S5. UPS spectra of the different assemblies, from (A) FTO/Au/Sb₂Se₃, to adding the TiO₂ layer (B), and up to adding the Au catalyst (C) showing the corresponding secondary electron cutoff energies and the valence band maxima/work function.

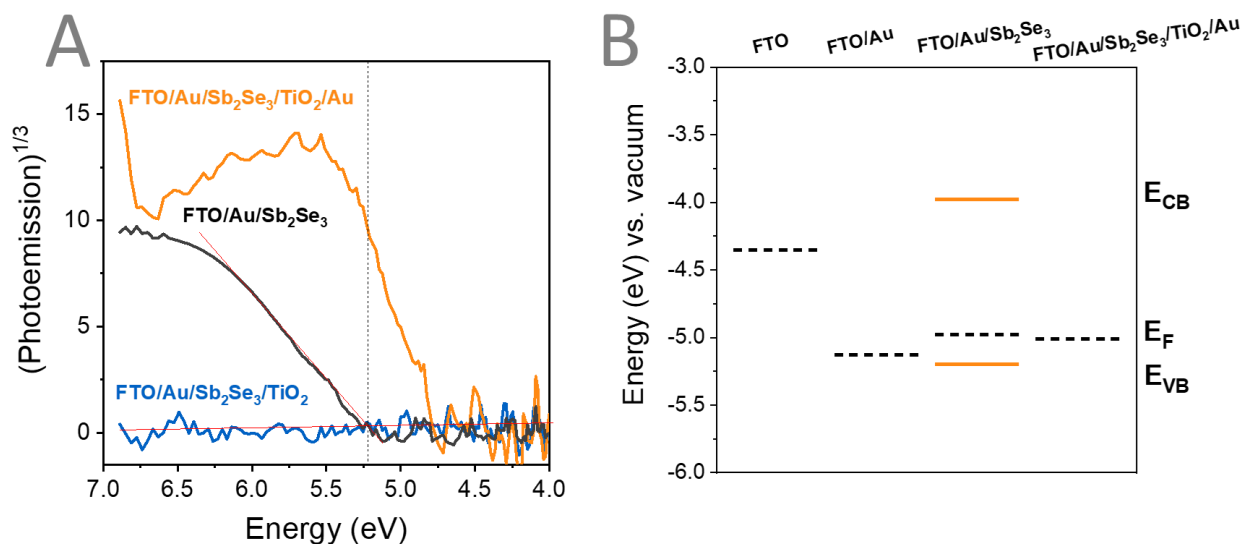


Figure S6. (A) Ambient Pressure Photoemission Spectra (APS) of the different assemblies. The APS curve of the FTO/Au/Sb₂Se₃ is used to determine the valence band position shown in (B). APS measurements were obtained at the range of 180nm-310nm. (B) Band diagram determined by contact potential difference, surface photovoltage spectroscopy, and ambient pressure photoemission spectroscopy measurements shown in Table S3. The valence band position of TiO₂ ($E_{VB} = 7.4$ eV) was outside the limit of the APS instrument (6.9 eV).

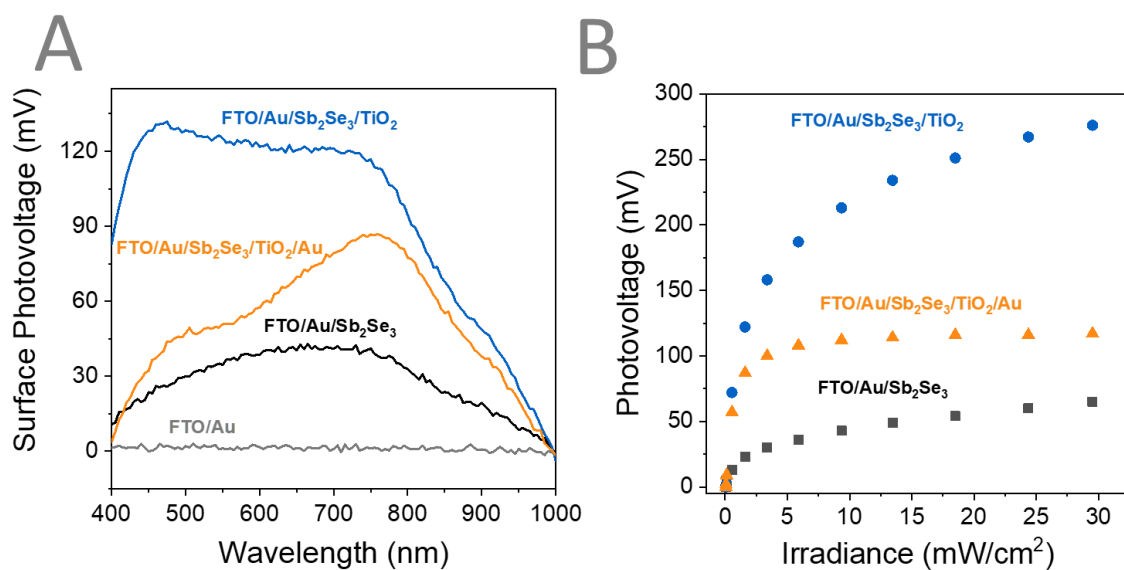


Figure S7. (A) Surface photovoltage spectra recorded in the wavelength range of 1000 nm – 400 nm and (B) Surface photovoltage measurements with white light illumination recorded for different intensities for the different photoelectrode assemblies.

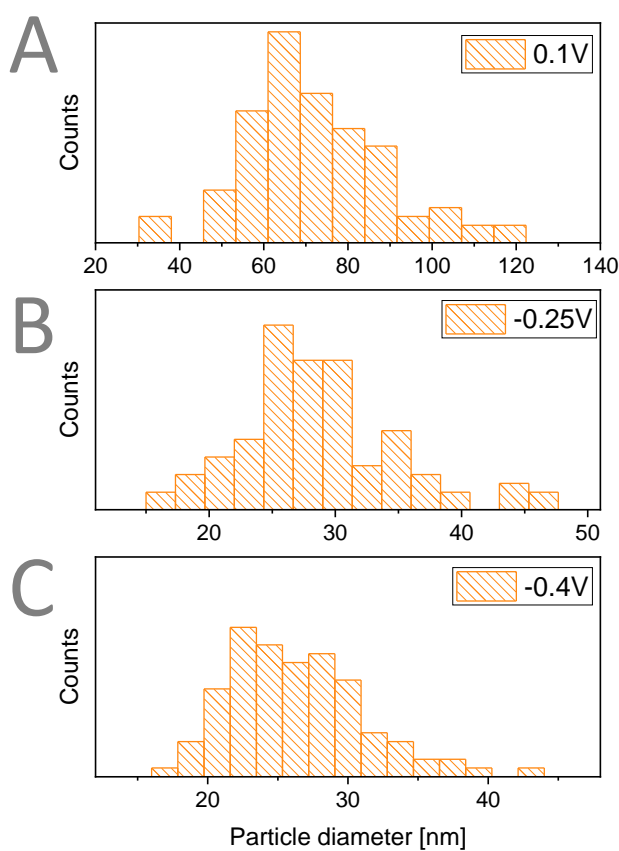


Figure S8. Size distribution of the Au nanoparticles for a total passed charge of 25 mC cm⁻² deposited at (A) 0.1V, (B) -0.25V, and (C) -0.4V vs Ag/AgCl. Particle diameters are obtained through ImageJ processing.

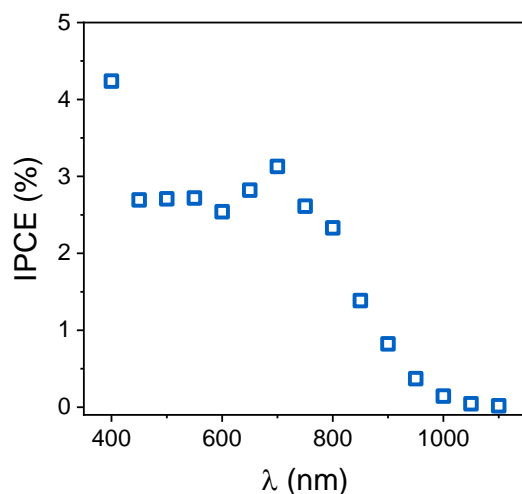


Figure S9. Incident-photon-to-current-efficiency (IPCE) curve of the FTO/Au/Sb₂Se₃/TiO₂/Au photoelectrode using potentiostatic measurement at -1.0 V vs. Ag/AgCl (-0.37 V vs RHE).

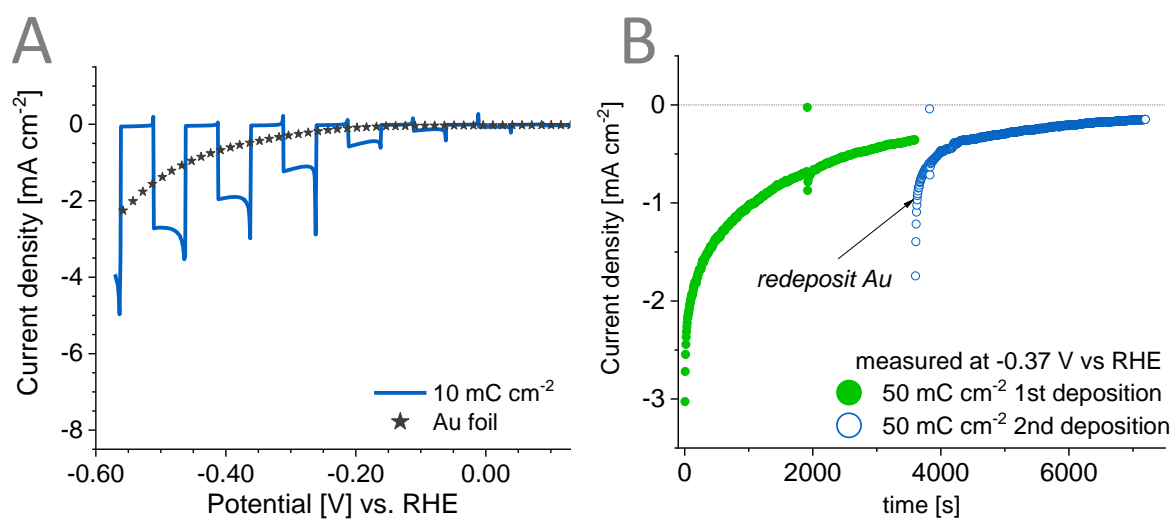


Figure S10. Performance of FTO/Au/Sb₂Se₃/TiO₂/Au photoelectrode with (A) lower amount of Au catalyst: 10 mC cm⁻² deposited at -0.25V vs Ag/AgCl and (B) when the Au was redeposited after 1 hour of long-term measurement at -0.37V vs RHE. Initial amount was 50 mC cm⁻² at -0.25V vs Ag/AgCl and redeposition was also performed with 50 mC cm⁻².

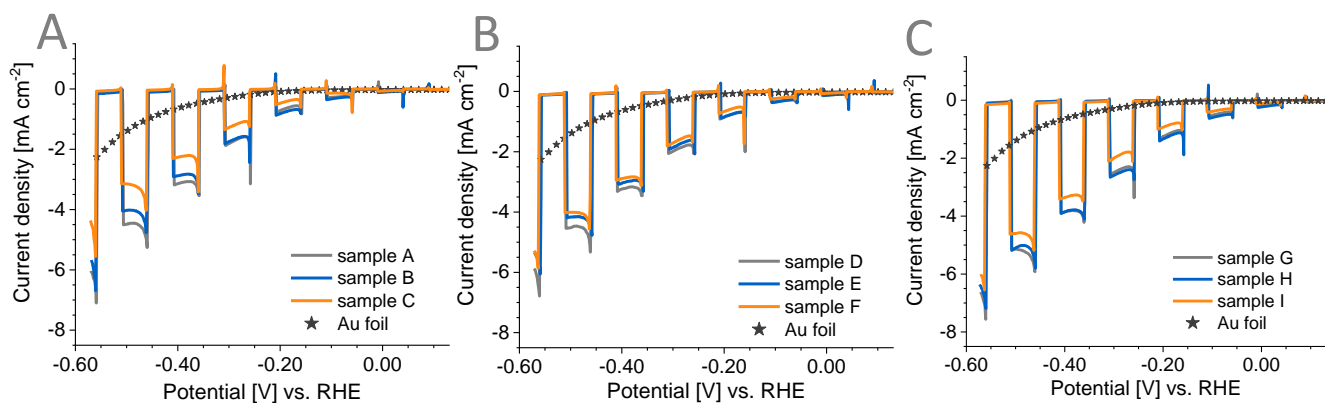


Figure S11. Performance of FTO/Au/Sb₂Se₃/TiO₂/Au photoelectrodes with different amount of Au catalyst: (A) 25 mC cm⁻², (B) 50 mC cm⁻² and (C) 75 mC cm⁻² deposited at an applied bias of -0.25V vs Ag/AgCl.

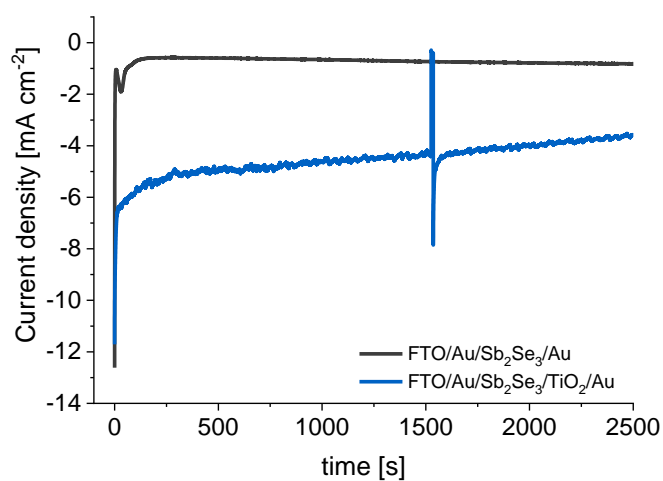


Figure S12. Chronoamperogram of the photoelectrode without the TiO₂ layer showing its poor performance. Both measured at -1.2 V vs Ag/AgCl (-0.57 V vs RHE) under 1 sun illumination (AM1.5G, 100 mW cm⁻²) in CO₂-saturated solution of 0.5 M KHCO₃.

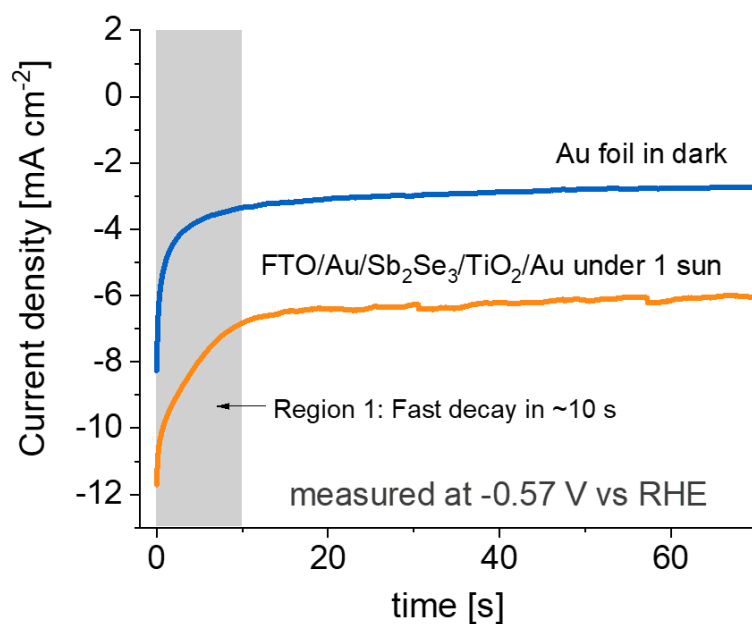


Figure S13. Chronoamperometry curve of a Au foil under similar conditions shows that the initial decay is inherent to Au. The same cell holder with the same exposed area was used for testing the Au foil and the photoelectrode. The electrolyte used is CO₂-saturated 0.5M KHCO₃ with continuous bubbling and stirring.

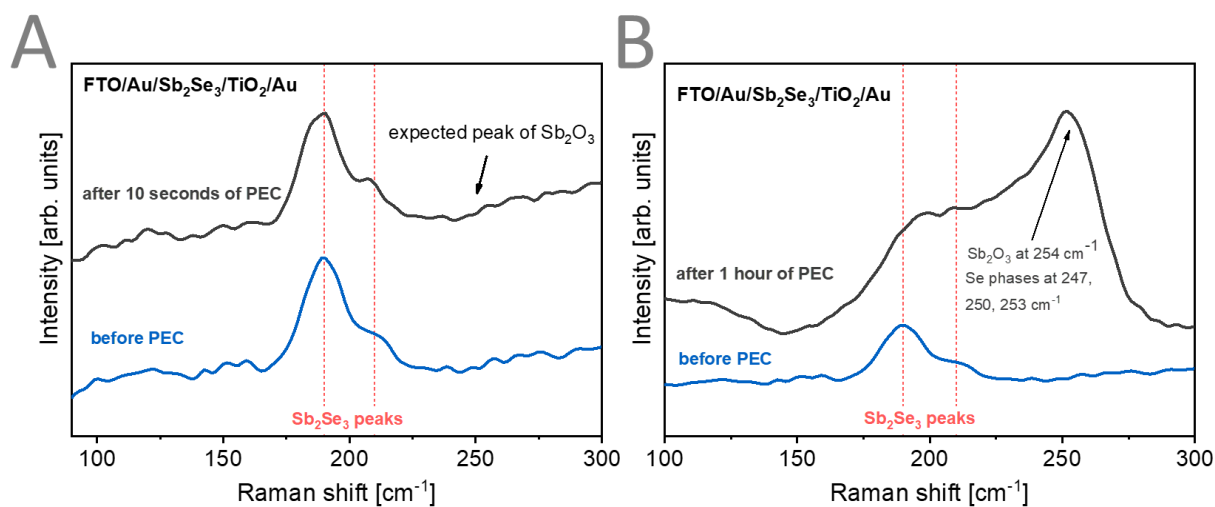


Figure S14. Post-PEC Raman spectra of the photoelectrode after (A) 10 seconds and (B) 1 hour of photoelectrolysis.

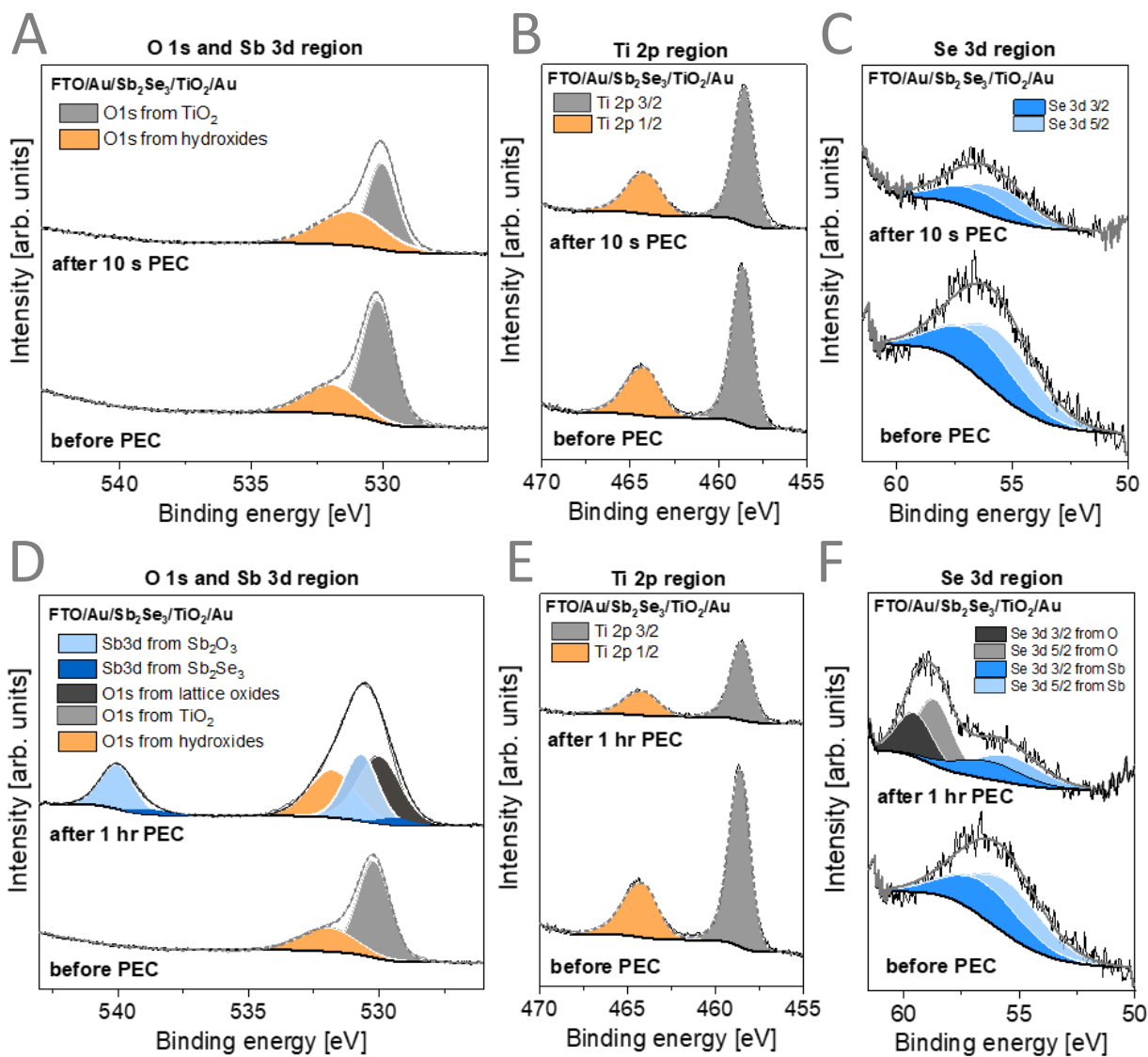


Figure S15. Post-PEC XPS spectra of the photoelectrode after 10 seconds (A, B, C) and 1 hour (D, E, F) of photoelectrolysis.

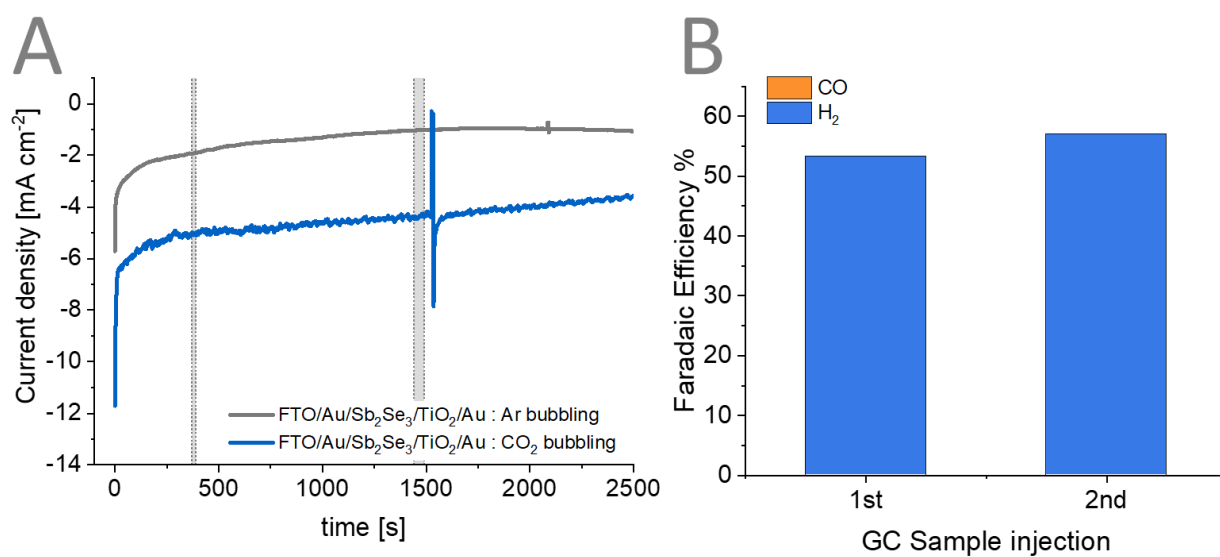


Figure S16. Chronoamperometry curve recorded using Ar bubbling vs CO₂ bubbling both measured at -0.57 V vs RHE. (B) Faradaic efficiency for the photoelectrolysis performed with Ar bubbling

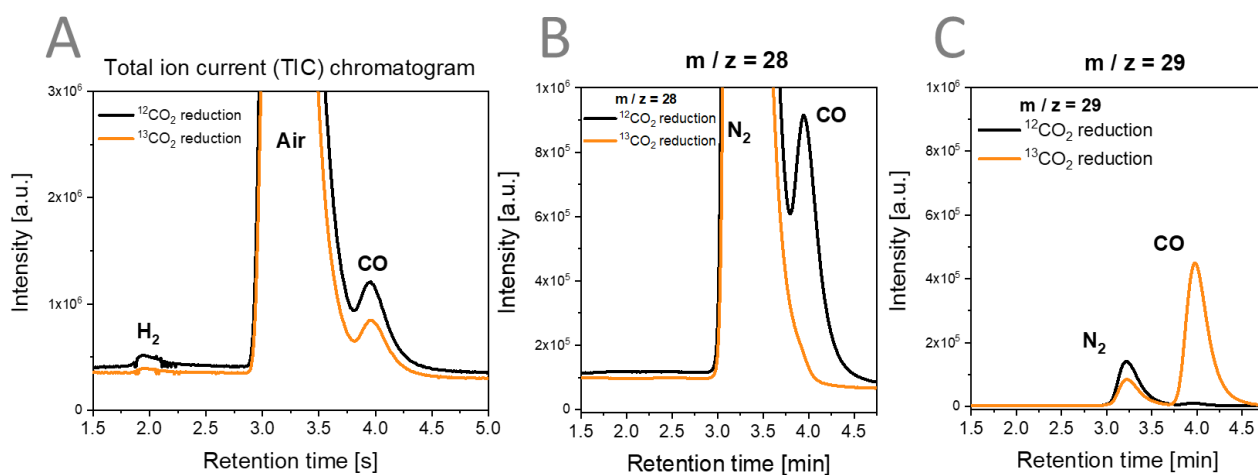


Figure S17. (A) Total ion current chromatogram and Selected-ion monitoring chromatograms at (B) $m/z = 28$ and at (C) $m/z = 29$ for the Isotope-labeled experiment wherein ¹³CO₂ and KH¹³CO₃ were used to identify the source of the CO product.

Tables

Table S1. Raman spectroscopy shifts with corresponding symmetry of Sb₂Se₃ from literature.

	Symmetry	Raman shift [cm ⁻¹]	Reference
Sb ₂ Se ₃	A _{2g}	190	3
		191	4
		190	5
	A _{1g}	213	3
		211	4
		215	5
Sb ₂ O ₃	A _g	253	4
		254	5
Se	A _{1g}	247	5,6
	E _u	253	5,6

Table S2. Binding energies for different species obtained experimentally versus data according to literature.

Species	Experimental Binding energy [eV] pristine samples	Experimental Binding energy [eV] after 1 hr photo-electrolysis (from Figure S15)	Literature Binding energy [eV] ^{with Reference}
(Sb ₂ Se ₃) Sb 3d 5/2	529.17	529.37	530.4 ⁸ 529.65 (fresh) ⁹ 529.92 (etched) ⁹ 529.6 ¹⁰
(Sb ₂ Se ₃) Sb 3d 3/2	538.51	538.71	539.02 (fresh) ⁹ 538.87 (etched) ⁹ 538.9 ¹⁰
Se 3d 5/2	53.61	58.62	54.23 ⁹ 55.0 ¹¹ 54.3 ¹⁰
Se 3d 3/2	54.47	59.48	55.07 ⁹ 55.8 ¹¹ 55.1 ¹⁰
(Sb ₂ O ₃) Sb 3d 5/2	530.38	530.68	531.2 ⁸ 530.1 ¹² 530 ¹³
O 1s	532.56	-	533.7 ⁸ 532.91 ⁹
Ti 2p 3/2	458.33	458.46	459.0 ¹⁴ 460 ¹⁵

**Fresh* and *etched* differentiates samples that have been plasma-etched

Table S3. Band diagram values according to Contact Potential Difference, Surface Photovoltage Spectroscopy, and Ambient Pressure Photoemission Spectroscopy results. The values presented in italic are not included in the band diagram in **Figure S6B**.

SPECIMEN	E_{VB} (EV)	E_F (EV)	E_{CB} (EV)	E_G (EV)
FTO		-4.35 ± 0.05		
FTO/Au		-5.13 ± 0.03		
FTO/Au/Sb ₂ Se ₃	-5.20 ± 0.02	-4.98 ± 0.02	-3.98	1.22^*
FTO/Au/Sb ₂ Se ₃ /TiO ₂		-4.43 ± 0.02		
FTO/Au/Sb ₂ Se ₃ /TiO ₂ /Au		-5.01 ± 0.03		

*data from **Figure S3**

Table S4. Summary of photoelectrode performances in CO₂RR for CO production in aqueous electrolytes.

Assembly	Photocurrent density (mA cm ⁻²)	Electrolyte	Illumination intensity (mW cm ⁻²)	Faradaic efficiency for CO	Reference
FTO/Au/Sb₂Se₃/TiO₂/Au	7.5 at $-0.57 V_{RHE}$	0.5 M KHCO₃	100	30% at $-0.57 V_{RHE}$	This work
p-i-n a-Si/TiO ₂ /Au _{GB}	5 at $-0.1 V_{RHE}$	0.1 M KHCO ₃	100	50% at $-0.1 V_{RHE}$	12
pn ⁺ -Si/GaN _{NW} /Au	21 at $-0.2 V_{RHE}$	0.5 M KHCO ₃	100	35% at $+0.17 V_{RHE}$	13
InP _{NW} /Au-TiO ₂	5 at $-0.1 V_{RHE}$	0.1 M KHCO ₃	100	84.2% at $-0.1 V_{RHE}$	14
ZnO/ZnTe/Au	16 at $-0.7 V_{RHE}$	0.5 M KHCO ₃	100	63% at $-0.5 V_{RHE}$	15
pn ⁺ -Si NW/Au ₃ Cu	7 at $-0.5 V_{RHE}$	0.1 M KHCO ₃	33.33	80% at $-0.2 V_{RHE}$	16
pn ⁺ -Si/Au	7.5 at $-0.5 V_{RHE}$	0.2 M KHCO ₃	100	91% at $-0.03 V_{RHE}$	17
pn ⁺ -Si/TiO ₂ /Au	8 at $-0.8 V_{RHE}$	0.1 M KHCO ₃	100	86% at $-0.8 V_{RHE}$	18
Si/Au _{buried}	13.1 at $-1.0 V_{RHE}$	0.1 M KHCO ₃	100	82.2% at $-0.4 V_{RHE}$	19

*NW subscript = nanowires, GB = grain boundaries

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